## CD4051BM/CD4051BC Single 8-Channel Analog Multiplexer/Demultiplexer CD4052BM/CD4052BC Dual 4-Channel Analog Multiplexer/Demultiplexer CD4053BM/CD4053BC Triple 2-Channel Analog Multiplexer/Demultiplexer

#### **General Description**

These analog multiplexers/demultiplexers are digitally controlled analog switches having low "ON" impedance and very low "OFF" leakage currents. Control of analog signals up to  $15\mathrm{V_{P-p}}$  can be achieved by digital signal amplitudes of  $3-15\mathrm{V}$ . For example, if  $\mathrm{V_{DD}}=5\mathrm{V}$ ,  $\mathrm{V_{SS}}=0\mathrm{V}$  and  $\mathrm{V_{EE}}=-5\mathrm{V}$ , analog signals from  $-5\mathrm{V}$  to  $+5\mathrm{V}$  can be controlled by digital inputs of  $0-5\mathrm{V}$ . The multiplexer circuits dissipate extremely low quiescent power over the full  $\mathrm{V_{DD}}-\mathrm{V_{SS}}$  and  $\mathrm{V_{DD}}-\mathrm{V_{EE}}$  supply voltage ranges, independent of the logic state of the control signals. When a logical "1" is present at the inhibit input terminal all channels are "OFF".

CD4051BM/CD4051BC is a single 8-channel multiplexer having three binary control inputs. A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned "ON" and connect the input to the output.

CD4052BM/CD4052BC is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 or 4 pairs of channels to be turned on and connect the differential analog inputs to the differential outputs.

CD4053BM/CD4053BC is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and

an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole double-throw configuration.

#### **Features**

- Wide range of digital and analog signal levels: digital 3-15V, analog to 15V<sub>p-p</sub>
- Low "ON" resistance: 80Ω (typ.) over entire 15V<sub>p-p</sub> signal-input range for V<sub>DD</sub>−V<sub>EE</sub>=15V
- High "OFF" resistance: channel leakage of ±10 pA (typ.) at V<sub>DD</sub>-V<sub>EE</sub>=10V
- Logic level conversion for digital addressing signals of 3-15V (V<sub>DD</sub>-V<sub>SS</sub>=3-15V) to switch analog signals to 15 V<sub>P</sub>-p (V<sub>DD</sub>-V<sub>EE</sub>=15V)
- $\blacksquare$  Matched switch characteristics:  $\Delta R_{ON}\!=\!5\Omega$  (typ.) for  $V_{DD}\!-\!V_{EE}\!=\!15V$
- Very low quiescent power dissipation under all digitalcontrol input and supply conditions: 1 µW (typ.) at VDD-VSS=VDD-VEE=10V
- Binary address decoding on chip

#### **Connection Diagrams**

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#### **Absolute Maximum Ratings**

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V<sub>DD</sub>)  $-0.5 \text{ V}_{DC} \text{ to } +18 \text{ V}_{DC}$  Input Voltage (V<sub>IN</sub>)  $-0.5 \text{ V}_{DC} \text{ to } V_{DD} +0.5 \text{ V}_{DC}$  Storage Temperature Range (T<sub>S</sub>)  $-65^{\circ}\text{C to } +150^{\circ}\text{C}$  Power Dissipation (P<sub>D</sub>)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temp. (T<sub>L</sub>) (soldering, 10 sec.) 260°C

# Recommended Operating Conditions

DC Supply Voltage (V<sub>DD</sub>)  $+5 \text{ V}_{DC} \text{ to } +15 \text{ V}_{DC}$  Input Voltage (V<sub>IN</sub>)  $0 \text{V to V}_{DD} \text{ V}_{DC}$ 

Operating Temperature Range (T<sub>A</sub>) 4051BM/4052BM/4053BM 4051BC/4052BC/4053BC

-55°C to +125°C -40°C to +85°C

#### **DC Electrical Characteristics** (Note 2)

Symbol	Parameter	Con	ditions		55°C	+ 25°			+ 125°C		Units
Symbol	raiametei		iditions	Min	Max	Min	Тур	Max	Min	Max	Oilles
I <sub>DD</sub>	Quiescent Device Current	V <sub>DD</sub> = 5V V <sub>DD</sub> = 10V V <sub>DD</sub> = 15V			5 10 20			5 10 20		150 300 600	μΑ μΑ μΑ
Signal In	puts (V <sub>IS</sub> ) and Outputs (V <sub>C</sub>	os)									
R <sub>ON</sub>	"ON" Resistance (Peak for V <sub>EE</sub> ≤V <sub>IS</sub> ≤V <sub>DD</sub> )	$R_L = 10 \text{ k}\Omega$ (any channel selected)	$V_{DD} = 2.5V, \ V_{EE} = -2.5V \ or V_{DD} = 5V, \ V_{EE} = 0V$		800		270	1050		1300	Ω
			$\begin{aligned} &V_{DD}\!=\!5V\\ &V_{EE}\!=\!-5V\\ &\text{or }V_{DD}\!=\!10V,\\ &V_{EE}\!=\!0V \end{aligned}$		310		120	400		550	Ω
			$V_{DD} = 7.5V, \ V_{EE} = -7.5V \ or V_{DD} = 15V, \ V_{EE} = 0V$		200		80	240		320	Ω
ΔR <sub>ON</sub>	Δ"ON" Resistance Between Any Two Channels	$R_L = 10 \text{ k}\Omega$ (any channel selected)	$V_{DD} = 2.5V, \ V_{EE} = -2.5V \ or V_{DD} = 5V, \ V_{EE} = 0V$				10				Ω
			$V_{DD} = 5V,$ $V_{EE} = -5V$ or $V_{DD} = 10V,$ $V_{EE} = 0V$				10				Ω
			$V_{DD} = 7.5V, \ V_{EE} = -7.5V \ or V_{DD} = 15V, \ V_{EE} = 0V$				5				Ω
	"OFF" Channel Leakage Current, any channel "OFF"	$V_{DD} = 7.5V,$ $O/I = \pm 7.5V, I$	V <sub>EE</sub> = -7.5V /O=0V		±50		± 0.01	±50		±500	nA
	"OFF" Channel Leakage	Inhibit = 7.5V	CD4051		±200		±0.08	±200		±2000	nA
	Current, all channels "OFF" (Common OUT/IN)	$V_{DD} = 7.5V,$ $V_{EE} = -7.5V,$ O/I = 0V,	CD4052		±200		±0.04	±200		±2000	nA
		I/O = ±7.5V	CD4053		±200		±0.02	±200		±2000	nA
	Inputs A, B, C and Inhibit	V _V _	-1 kO to V		l						
V <sub>IL</sub>	Low Level Input Voltage	$\begin{array}{c} V_{EE}\!=\!V_{SS}R_L\!=\!\\ I_{IS}\!<\!2\mu\text{A on al}\\ V_{IS}\!=\!V_{DD}\text{thru}\\ V_{DD}\!=\!5V\\ V_{DD}\!=\!10V\\ V_{DD}\!=\!15V \end{array}$	I OFF channels		1.5 3.0 4.0			1.5 3.0 4.0		1.5 3.0 4.0	V V
V <sub>IH</sub>	High Level Input Voltage	V <sub>DD</sub> =5 V <sub>DD</sub> =10 V <sub>DD</sub> =15		3.5 7 11		3.5 7 11			3.5 7 11		V V V

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: All voltages measured with respect to V<sub>SS</sub> unless otherwise specified.

Symbol	Parameter	Conditions		-40°C		+ 25°C			+85°C		Units
Symbol	raiametei	001	iditions	Min	Max	Min	Тур	Max	Min	Max	Oille
I <sub>IN</sub>	Input Current	V <sub>DD</sub> =15V, V <sub>IN</sub> =0V V <sub>DD</sub> =15V,	V <sub>EE</sub> =0V V <sub>EE</sub> =0V		-0.1		-10-5	-0.1		-1.0	μA
		V <sub>IN</sub> =15V			0.1		10-5	0.1		1.0	μΑ
I <sub>DD</sub>	Quiescent Device Current	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$			20 40 80			20 40 80		150 300 600	μΑ μΑ μΑ
Signal In	puts (V <sub>IS</sub> ) and Outputs (V <sub>OS</sub>	)									
R <sub>ON</sub>	"ON" Resistance (Peak for $V_{EE} \le V_{IS} \le V_{DD}$ )	$R_L = 10 \text{ k}\Omega$ (any channel selected)	$V_{DD} = 2.5V,$ $V_{EE} = -2.5V$ or $V_{DD} = 5V,$ $V_{EE} = 0V$		850		270	1050		1200	Ω
			$V_{DD} = 5V,$ $V_{EE} = -5V$ or $V_{DD} = 10V,$ $V_{EE} = 0V$		330		120	400		520	Ω
			$\begin{aligned} &V_{DD}\!=\!7.5\text{V},\\ &V_{EE}\!=\!-7.5\text{V}\\ &\text{or }V_{DD}\!=\!15\text{V},\\ &V_{EE}\!=\!0\text{V} \end{aligned}$		210		80	240		300	Ω
ΔR <sub>ON</sub>	Δ"ON" Resistance Between Any Two Channels	$R_L = 10 \text{ k}\Omega$ (any channel selected)	$\begin{aligned} &V_{DD}\!=\!2.5V,\\ &V_{EE}\!=\!-2.5V\\ &\text{or }V_{DD}\!=\!5V,\\ &V_{EE}\!=\!0V \end{aligned}$				10				Ω
			$V_{DD} = 5V$ $V_{EE} = -5V$ or $V_{DD} = 10V$ $V_{EE} = 0V$				10				Ω
			$V_{DD} = 7.5V,$ $V_{EE} = -7.5V$ or $V_{DD} = 15V,$ $V_{EE} = 0V$				5				Ω
	"OFF" Channel Leakage Current, any channel "OFF"	$V_{DD} = 7.5V$ , $O/I = \pm 7.5V$ , I	V <sub>EE</sub> = -7.5V /O=0V		±50		±0.01	±50		±500	nA
	"OFF" Channel Leakage Current, all channels	Inhibit = $7.5V$ $V_{DD} = 7.5V$ ,	CD4051		±200 ±200		±0.08	±200		±2000	nA
	"OFF" (Common OUT/IN)	$V_{EE} = -7.5V,$ O/I = 0V	CD4052				±0.04	±200		±2000	nA
041	laanda A. D. O aad laabiisii	$I/O = \pm 7.5V$	CD4053	1	±200	1	±0.02	±200		±2000	nA
V <sub>IL</sub>	Inputs A, B, C and Inhibit  Low Level Input Voltage	V <sub>EE</sub> =V <sub>SS</sub> R <sub>L</sub>	- 1 kO to Vee	Т.							
VIL	Low Level Input voltage		II OFF Channels		1.5 3.0 4.0			1.5 3.0 4.0		1.5 3.0 4.0	V V V
V <sub>IH</sub>	High Level Input Voltage	V <sub>DD</sub> =5 V <sub>DD</sub> =10 V <sub>DD</sub> =15		3.5 7 11		3.5 7 11			3.5 7 11		V V V
I <sub>IN</sub>	Input Current	V <sub>DD</sub> =15V, V <sub>IN</sub> =0V V <sub>DD</sub> =15V,	V <sub>EE</sub> =0V V <sub>EE</sub> =0V		-0.1 0.1		-10 <sup>-5</sup>	-0.1 0.1		-1.0 1.0	μA μA

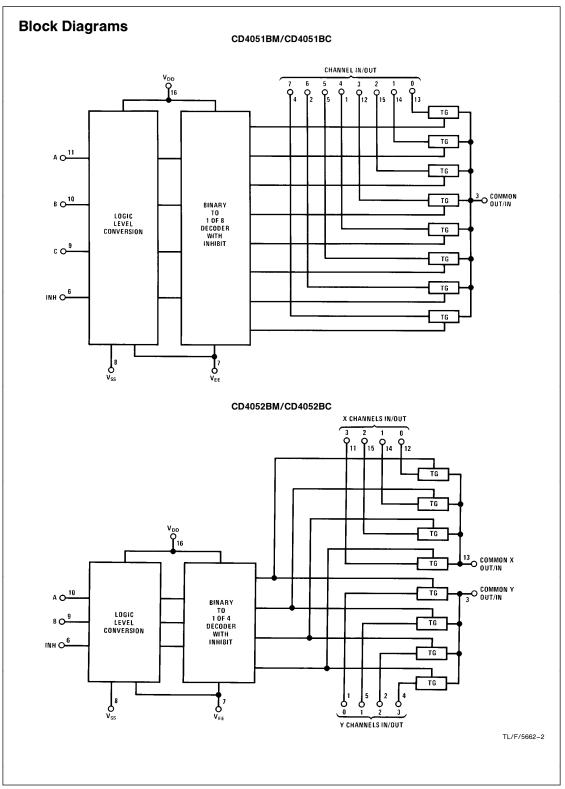
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

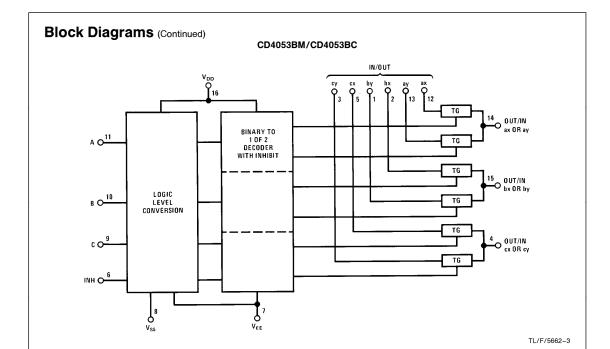
Note 2: All voltages measured with respect to  $\ensuremath{V_{SS}}$  unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	Min	Тур	Max	Units
t <sub>PZH,</sub> t <sub>PZL</sub>	Propagation Delay Time from Inhibit to Signal Output (channel turning on)	$V_{EE}=V_{SS}=0V$ $R_{L}=1 \text{ k}\Omega$ $C_{I}=50 \text{ pF}$	5V 10V 15V		600 225 160	1200 450 320	ns ns ns
t <sub>PHZ,</sub> t <sub>PLZ</sub>	Propagation Delay Time from Inhibit to Signal Output (channel turning off)	$V_{EE}=V_{SS}=0V$ $R_{L}=1 \text{ k}\Omega$ $C_{L}=50 \text{ pF}$	5V 10V 15V		210 100 75	420 200 150	ns ns ns
C <sub>IN</sub>	Input Capacitance Control input Signal Input (IN/OUT)				5 10	7.5 15	pF pF
C <sub>OUT</sub>	Output Capacitance (common OUT/IN)						
	CD4051 CD4052 CD4053	V <sub>EE</sub> =V <sub>SS</sub> =0V	10V 10V 10V		30 15 8		pF pF pF
C <sub>IOS</sub>	Feedthrough Capacitance				0.2		pF
$C_{PD}$	Power Dissipation Capacitance						
	CD4051 CD4052 CD4053				110 140 70		pF pF pF
Signal In	puts (V <sub>IS</sub> ) and Outputs (V <sub>OS</sub> )						
	Sine Wave Response (Distortion)	$\begin{array}{l} R_L \! = \! 10 \text{ k}\Omega \\ f_{1S} \! = \! 1 \text{ kHz} \\ V_{1S} \! = \! 5  V_{p\text{-}p} \\ V_{EE} \! = \! V_{SI} \! = \! 0V \end{array}$	10V		0.04		%
	Frequency Response, Channel "ON" (Sine Wave Input)	$R_L = 1 \text{ k}\Omega, V_{EE} = 0V, V_{IS} = 5V_{p-p},$ $20 \log_{10} V_{OS}/V_{IS} = -3 \text{ dB}$	10V		40		MHz
	Feedthrough, Channel "OFF"	$R_L = 1 \text{ k}\Omega$ , $V_{EE} = V_{SS} = 0V$ , $V_{IS} = 5V_{p-p}$ , $20 \log_{10} V_{OS}/V_{IS} = -40 \text{ dB}$	10V		10		MHz
	Crosstalk Between Any Two Channels (frequency at 40 dB)	$\begin{aligned} R_L &= 1 \text{ k}\Omega, V_{EE} = V_{SS} = 0 \text{V}, V_{IS}(A) = 5 \text{V}_{p\text{-}p} \\ 20 \log_{10} V_{OS}(B) / V_{IS}(A) &= -40 \text{ dB (Note 3)} \end{aligned}$	10V		3		MHz
t <sub>PHL</sub> t <sub>PLH</sub>	Propagation Delay Signal Input to Signal Output	$V_{EE} = V_{SS} = 0V$ $C_L = 50 \text{ pF}$	5V 10V 15V		25 15 10	55 35 25	ns ns ns
Control I	nputs, A, B, C and Inhibit						
	Control Input to Signal Crosstalk	$V_{EE} = V_{SS} = 0V$ , $R_L = 10 \text{ k}\Omega$ at both ends of channel. Input Square Wave Amplitude = 10V	10V		65		mV (peak)
t <sub>PHL,</sub> t <sub>PLH</sub>	Propagation Delay Time from Address to Signal Output (channels "ON" or "OFF")	V <sub>EE</sub> =V <sub>SS</sub> =0V C <sub>L</sub> =50 pF	5V 10V 15V		500 180 120	1000 360 240	ns ns ns

<sup>\*</sup>AC Parameters are guaranteed by DC correlated testing.

Note 3: A, B are two arbitrary channels with A turned "ON" and B "OFF".



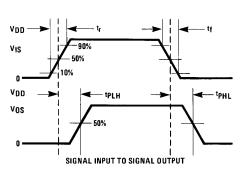


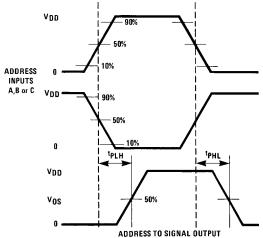
### **Truth Table**

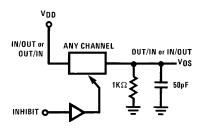
INPUT STATES				"ON" CHANNELS					
INHIBIT	С	В	Α	CD4051B	CD4052B	CD4053B			
0	0	0	0	0	0X, 0Y	cx, bx, ax			
0	0	0	1	1	1X, 1Y	cx, bx, ay			
0	0	1	0	2	2X, 2Y	cx, by, ax			
0	0	1	1	3	3X, 3Y	cx, by, ay			
0	1	0	0	4		cy, bx, ax			
0	1	0	1	5		cy, bx, ay			
0	1	1	0	6		cy, by, ax			
0	1	1	1	7		cy, by, ay			
1	*	*	*	NONE	NONE	NONE			

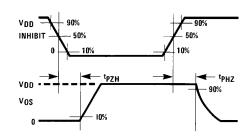
<sup>\*</sup>Don't Care condition.

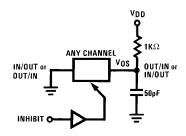


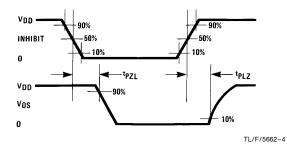










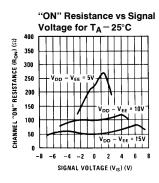


#### **Special Considerations**

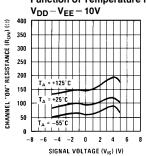
In certain applications the external load-resistor current may include both  $V_{DD}$  and signal-line components. To avoid drawing  $V_{DD}$  current when switch current flows into IN/OUT pin, the voltage drop across the bidirectional switch must

not exceed 0.6V at  $T_A{\leq}$  25°C, or 0.4V at  $T_A{>}$  25°C (calculated from  $R_{ON}$  values shown). No  $V_{DD}$  current will flow through  $R_L$  if the switch current flows into OUT/IN pin.

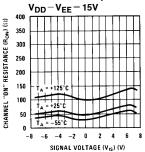
### **Typical Performance Characteristics**



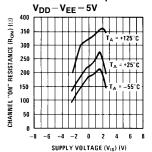
"ON" Resistance as a Function of Temperature for



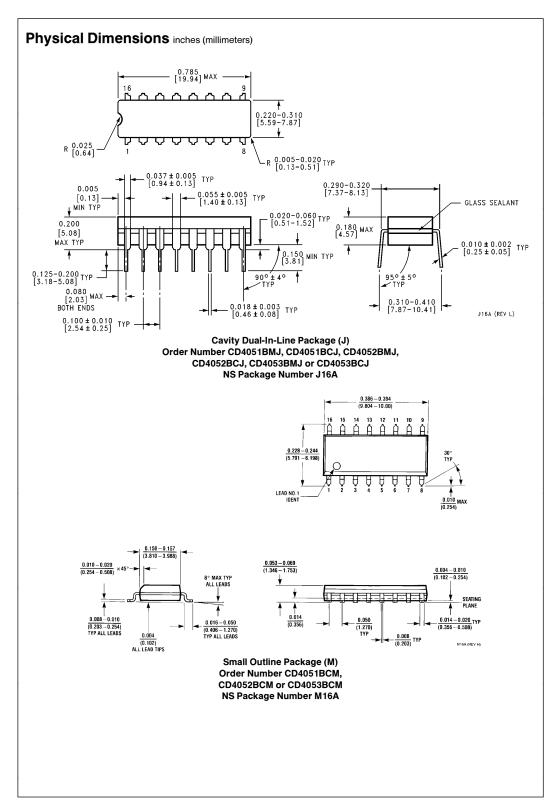
"ON" Resistance as a Function of Temperature for

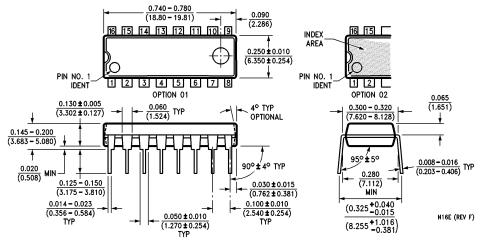


"ON" Resistance as a Function of Temperature for



TL/F/5662-5





Molded Dual-In-Line Package (N) Order CD4051BM, CD4051BC, CD4052BM, CD4052BC, CD4053BM, CD4053BC NS Package Number N16E

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